

P-Channel Enhancement Mode Field Effect Transistor

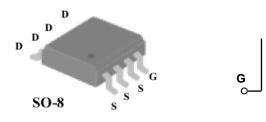
FEATURES

- Super high dense cell design for low RDS(ON)
- Rugged and reliable
- Simple drive requirement
- SOP-8 package

PRODUCT S	UMMARY		
Vdss	ID RDS(ON) (m Ω) Typ		
-30V	-8A	15@ VGS=-10V	
		22 @ VGS=-4.5V	



NOTE: The MT4435A is available in a lead-free package



ABSOLUTE MAXIUM RATINGS (TA=25 $^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-30	V
Gate-Source Voltage	VGS	±25	V
Drain Current-Continuous ^a @Tj=125 °C	Id	-8	А
- Pulse d^{b}	Ідм	-40	А
Drain-source Diode Forward Current ^a	Is	-2.4	А
Maximum Power Dissipation ^a	Pd	2.5	W
Operating Junction and Storage Temperature Range	Тл,Тятб	-55 to 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to Ambient ^a Rth JA50°C/W



ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						1
Drain-Source Breakdown Voltage	BVDSS	Vgs=0V,Id=-250µA	-30			V
Zero Gate Voltage Drain Current	IDSS	VDS=-24V,VGS=0V			-1	μA
Gate-Body Leakage	Igss	Vgs=±20V,Vds=0V			±100	nA
ON CHARACTERITICS						
Gate Threshold Voltage	VGs(th)	VDS=VGS,ID=-250µA	-1	-1.6	-2.5	V
Durin Course On State Desistance	Drawn	Vgs=-10V,Id=-8A		15	20	mΩ
Drain-Source On-State Resistance	RDS(ON)	Vgs=-4.5V,ID=-5.0A		22	35	
Forward Transconductance	gFS	Vgs=-15V,Id=-8A		6		S
DAYNAMIC CHARACTERISTICS						
Input Capacitance	Ciss	Vds=-15V,Vgs=0V f=1.0MHz		1119		pF
Output Capacitance	Coss			363		pF
Reverse Transfer Capacitance	Crss			138		pF
SWITCHING CHARACTERISISTICS				•	•	I
Turn-On Delay Time	td(on)	VDD=-15V		17.8		ns
Rise Time	tr	ID=-8A, VGEN=-4.5V RL=10ohm RGEN=60hm		17.5		ns
Turn-Off Delay Time	td(OFF)			169		ns
Fall Time	tf			96		ns
Total Gate Charge	Qg	Vds=-15V,Id=-1A Vgs=-10V		35		nC
Gate-Source Charge	Qgs			3.3		nC
Gate-Drain Charge	Qgd			8.1		nC



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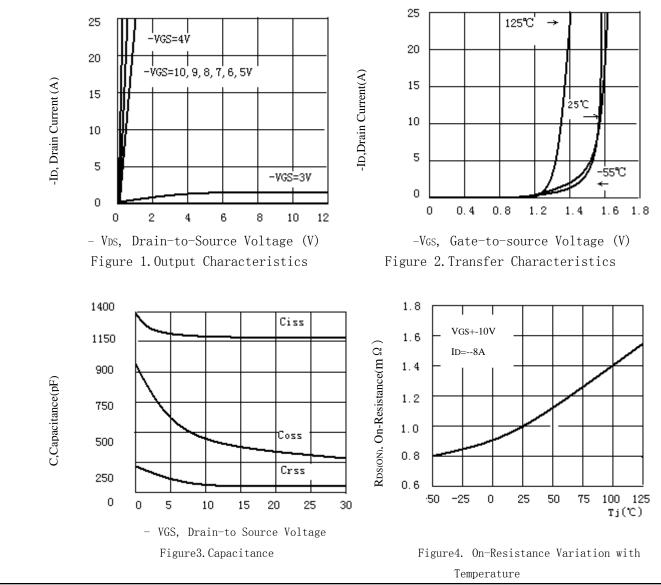
MT4435A

ELECTRICAL CHARACTERICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
DRAIN-SOURCE DIODE CHARACT	ERISTICS			_	_	
Diode Forward Voltage	Vsd	Vgs=0V,Is=-1.7A		-0.74	-1.2	V

Notes

- a. Surface Mounted on FR4 Board, $t \leq 10$ sec
- b. Pulse Test: Pulse Width \leq 300Us, Duty \leq 2%
- c. Guaranteed by design, not subject to production testing.

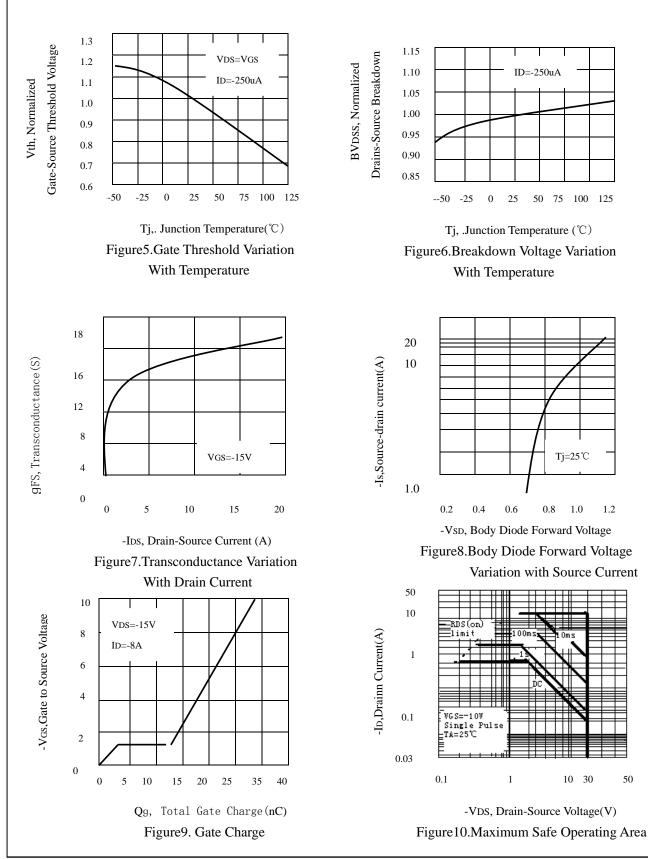


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MT4435A



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